

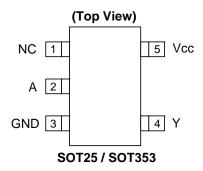
Description

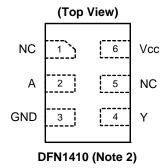
The 74LVCE1G07 is a single inverter gate with an open drain output. The device is designed for operation with a power supply range of 4V to 5.5V. The input is tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down. The open-drain output can be connected to other open drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32 mA.

Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments





Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- · Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

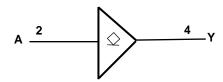
2. Pin 2 and pin 5 of the DFN1410 package are internally connected.



Pin Descriptions

Pin Name	Description			
NC	No connection			
А	Data Input			
GND	Ground			
Υ	Data Output Open Drain			
Vcc	Supply Voltage			

Logic Diagram



Function Table

Inputs	Output
Α	Υ
Н	Z
L	L



Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
Vı	Input Voltage Range	-0.5 to 6.5	V
V _o	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
V _o	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
	Continuous current through Vdd or GND		mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit	
	Operating Voltage	Operating	1.4	5.5	V	
V _{CC}	Operating Voltage	Data retention only	1.2		V	
		V _{CC} = 1.4 V to 1.95 V	0.65 X V _{CC}			
\/	High level lengt Voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V	
V _{IH}	High-level Input Voltage	V _{CC} = 3 V to 3.6 V	2		V	
		V _{CC} = 4.5 V to 5.5 V	0.7 X V _{CC}			
	V _{IL} Low-level input voltage	V _{CC} = 1.4 V to 1.95 V		0.35 X V _{CC}		
\/		V _{CC} = 2.3 V to 2.7 V		0.7	.,	
VIL		V _{CC} = 3 V to 3.6 V		0.8	V	
		V _{CC} = 4.5 V to 5.5 V		0.3 X V _{CC}		
Vı	Input Voltage	0	5.5	V		
Vo	Output Voltage		0	V _{CC}	V	
		Vcc=1.4 V		3		
		V _{CC} = 1.65 V		4		
	Lave lavel autaut aumant	V _{CC} = 2.3 V		8		
I _{OL}	Low-level output current	V 2V		16	mA	
		$V_{CC} = 3 V$		24		
		V _{CC} = 4.5 V		32		
		V _{CC} = 1.4 V to 3.0 V		20		
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 3.3 V ± 0.3 V		10	ns/V	
	iale	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5		
T _A	Operating free-air temperature		-40	85	°C	

Notes: 4. Unused inputs should be held at Vcc or Ground.



Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit	
	I _{OL} = 100 μA	1.4 V to 5.5 V			0.1		
	$I_{OL} = 3 \text{ mA}$	1.4 V			0.4		
	I _{OL} = 4 mA	1.65 V			0.45		
	$I_{OL} = 8 \text{ mA}$	2.3 V			0.3	V	
- Cutput voltago	I _{OL} = 16 mA	2.1/			0.4		
	I _{OL} = 24 mA	3 V			0.55		
	I _{OL} = 32 mA	4.5 V			0.55		
Input Current	V _I = 5.5 V or GND	0 to 5.5 V			± 5	μA	
Z State Leakage Current	V _O = 5.5V	3.6 V			± 10	μA	
Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0 V			± 10	μA	
Supply Current	$V_1 = 5.5 \text{ V or GND } I_0 = 0$	1.4 V to 5.5 V			10	μΑ	
Additional Supply Current	Input at V _{CC} –0.6 V	3 V to 5.5 V			500	μA	
Input Capacitance	V _I = V _{CC} or GND	3.3V		4		pF	
Output Capacitance	V _O = V _{CC} or GND	3.3V		5		pF	
	SOT25	(Note 5)		204			
	SOT353	(Note 5)		371		°C/W	
direction to edge	DFN1410	(Note 5)		430			
	SOT25	(Note 5)		52			
	SOT353	(Note 5)		143		°C/W	
	Parameter Low Level Output Voltage Input Current Z State Leakage Current Power Down Leakage Current Supply Current Additional Supply Current Input Capacitance	$Low \ Level \ Output \ Voltage$ $Low \ Level \ Io_{L} = 4 \ mA$ $Lo_{L} = 4 \ mA$ $Lo_{L} = 16 \ mA$ $Lo_{L} = 16 \ mA$ $Lo_{L} = 24 \ mA$ $Lo_{L} = 32 \ mA$ $Low \ Low \ Low \ Io_{L} = 36 \ mA$ $Low \ Low \ Io_{L} = 36 \ mA$ $Low \ Low \ Io_{L} = 4 \ mA$ $Low \ Io_{L} = 8 \ mA$ $Low \ Io$	$ \begin{array}{ c c c c c } \hline \textbf{Parameter} & \textbf{Test Conditions} & \textbf{Vcc} \\ \hline \\ I_{OL} = 100 \ \mu A & 1.4 \ V to 5.5 \ V \\ \hline \\ I_{OL} = 3 \ mA & 1.4 \ V \\ \hline \\ I_{OL} = 4 \ mA & 1.65 \ V \\ \hline \\ I_{OL} = 8 \ mA & 2.3 \ V \\ \hline \\ I_{OL} = 16 \ mA & 3 \ V \\ \hline \\ I_{OL} = 24 \ mA & 4.5 \ V \\ \hline \\ Input Current & V_1 = 5.5 \ V \ or \ GND & 0 \ to 5.5 \ V \\ \hline Z \ State \\ Leakage \ Current & V_1 = 5.5 \ V \ or \ GND & 0 \ vo 5.5 \ V \\ \hline Power \ Down \ Leakage \\ Current & V_1 = 5.5 \ V \ or \ GND \ I_{O} = 0 & 1.4 \ V to 5.5 \ V \\ \hline Supply \ Current & V_1 = 5.5 \ V \ or \ GND \ I_{O} = 0 & 1.4 \ V to 5.5 \ V \\ \hline Additional \ Supply \\ Current & Input \ Capacitance & V_1 = V_{CC} \ or \ GND & 3.3 \ V \\ \hline Output \ Capacitance & V_0 = V_{CC} \ or \ GND & 3.3 \ V \\ \hline Thermal \ Resistance \\ \hline Junction-to-Case & SOT353 & (Note 5) \\ \hline Thermal \ Resistance \\ \hline Thermal \ Resistance & SOT25 & (Note 5) \\ \hline \hline Thermal \ Resistance \\ \hline \end{tabular}$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{ c c c c c c } \hline \textbf{Parameter} & \textbf{Test Conditions} & \textbf{Vcc} & \textbf{Min} & \textbf{Typ} \\ \hline \\ I_{OL} = 100 \ \mu A & 1.4 \ \forall \ to \ 5.5 \ \forall \\ \hline \\ I_{OL} = 3 \ mA & 1.4 \ \forall \\ \hline \\ I_{OL} = 4 \ mA & 1.65 \ \forall \\ \hline \\ I_{OL} = 8 \ mA & 2.3 \ \forall \\ \hline \\ I_{OL} = 16 \ mA & 3 \ \forall \\ \hline \\ I_{OL} = 24 \ mA & 4.5 \ \forall \\ \hline \\ I_{OL} = 32 \ mA & 4.5 \ \forall \\ \hline \\ Input Current & V_1 = 5.5 \ \forall \ or \ GND & 0 \ to \ 5.5 \ \forall \\ \hline \\ Z \ State \\ Leakage \ Current & V_1 = 5.5 \ \forall \ or \ GND & 0 \ \forall \\ \hline \\ Supply \ Current & V_1 = 5.5 \ \forall \ or \ GND \ I_{O=0} & 1.4 \ \forall \ to \ 5.5 \ \forall \\ \hline \\ Additional \ Supply \\ Current & V_1 = V_{CC} \ or \ GND & 3.3 \ \forall \\ \hline \\ Input \ Capacitance & V_1 = V_{CC} \ or \ GND & 3.3 \ \forall \\ \hline \\ Thermal \ Resistance \ Thermal \ Resistance & SOT25 & (Note 5) & 371 \\ \hline \\ SOT25 & (Note 5) & 52 \\ \hline \\ Thermal \ Resistance & SOT25 &$		

Notes: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Switching Characteristics

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From	то	Vcc = ± 0.			: 1.8 V .15V		: 2.5 V).2V		3.3 V 3.3 V	Vcc :	= 5 V).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	A	Y	1.5	9.9	1	5.8	0.8	4.4	0.8	3.4	0.8	3.1	ns

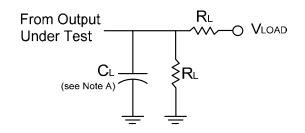
Operating Characteristics

 $T_A = 25$ °C

P	arameter		Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
	Condition		TYP	TYP	TYP	TYP	TYP	
C _{pd}	Power dissipation capacitance	f = 10 MHz	3	3	3	4	6	pF



Parameter Measurement Information



TEST	Condition
t _{PLZ} (see Notes D and E)	Vload
t _{PZL} (see Notes D and F)	Vload

Vcc	Inputs		V _M	V _{LOAD}	CL	RL	VΔ
	Vı	t _r /t _f	- 141	LOAD			
1.8V±0.15V	V _{cc}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	1ΚΩ	0.15V
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	V _{cc}	≤2.5ns	V _{CC} /2	2 X V _{CC}	50pF	500Ω	0.3V

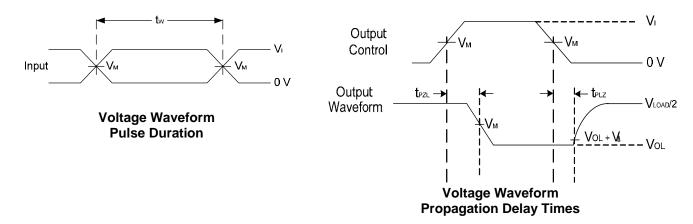


Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}
- E. t_{PZL} is measured at V_M . F. t_{PLZ} is measured at V_{OL} + V_{Δ}



Ordering Information

T4LVCE1G 07 XXX - 7

Logic Device Function Package Packing

74: Logic Prefix 07: Buffer/Driver W5: SOT25 7: Tape & Reel

LVCE: 1.4 to 5.5V With Open Drain SE: SOT353

Family FZ4: DFN1410

1G: One gate

Dovice	Device Package Packaging		7" Tape and Reel		
Device	Code	(Note 6)	Quantity	Part Number Suffix	
74LVCE1G07W5-7	W5	SOT25	3000/Tape & Reel	-7	
74LVCE1G07SE-7	SE	SOT353	3000/Tape & Reel	-7	
74LVCE1G07FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7	

Notes: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Marking Information

(1) SOT25 and SOT353

(Top View)

4 XX Y WX

2

XX: Identification code

Y: Year 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Internal code

Part Number	Package	Identification Code
74LVCE1G07W5	SOT25	PN
74LVCE1G07SE	SOT353	PN

(3) DFN1410

(Top View)

3

<u>XX</u> $\underline{Y}\underline{W}\underline{X}$ XX: Identification Code

Y: Year: 0~9

 \overline{W} : Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

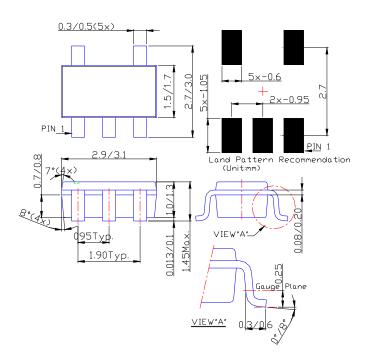
52 and 53 week X: A~Z: Internal code

Part Number	Package	Identification Code
74LVCE1G07FZ4	DFN1410	PN

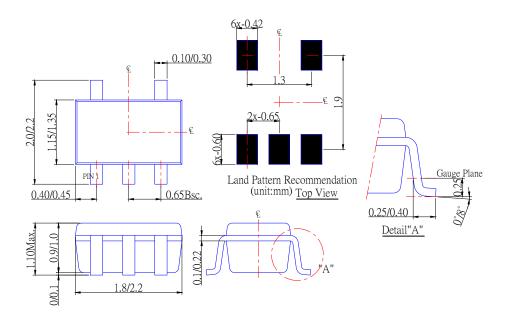


Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



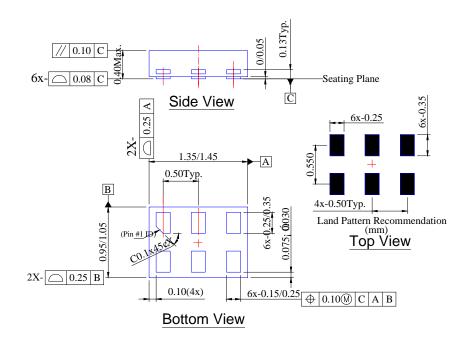
(2) Package Type: SOT353





Package Outline Dimensions (Continued)

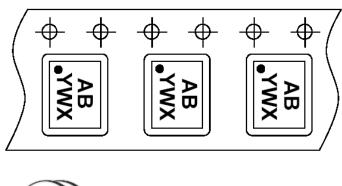
(3) Package Type: DFN1410

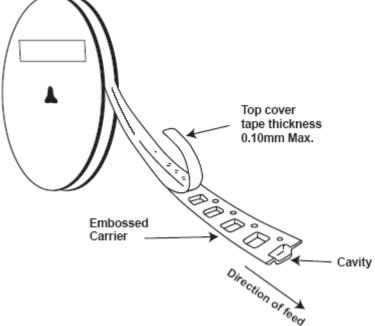




Taping Orientation (Note 7)

For DFN1410





Notes: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf



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